# Triple Schmitt-Trigger Inverter

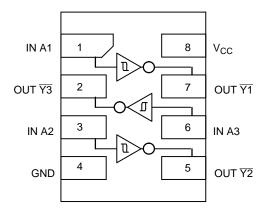
The NLU3G14 MiniGate<sup>™</sup> is an advanced high–speed CMOS triple Schmitt–trigger inverter in ultra–small footprint.

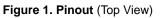
The NLU3G14 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

The NLU3G14 can be used to enhance noise immunity or to square up slowly changing waveforms.

## Features

- High Speed:  $t_{PD} = 4.0 \text{ ns} (Typ) @ V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 1 \ \mu A$  (Max) at  $T_A = 25^{\circ}C$
- Power Down Protection Provided on inputs
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These are Pb–Free Devices





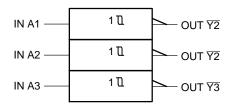


Figure 2. Logic Symbol

#### FUNCTION TABLE

A	Ŷ			
L H	H L			

#### PIN ASSIGNMENT

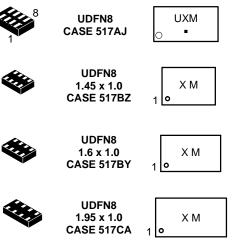
1	IN A1				
2	OUT <del>T</del> 3				
3	IN A2				
4	GND				
5	OUT 72				
6	IN A3				
7	OUT Y1				
8	V <sub>CC</sub>				



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# MARKING DIAGRAMS



UX, A or LA = Specific Device Code M = Date Code

= Pb–Free Package

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

### **MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage	-0.5 to +7.0	V
V <sub>OUT</sub>	DC Output Voltage	-0.5 to +7.0	V
Ι <sub>ΙΚ</sub>	DC Input Diode Current V <sub>IN</sub> < GND	-20	mA
Ι <sub>ΟΚ</sub>	DC Output Diode Current V <sub>OUT</sub> < GND	±20	mA
Ι <sub>Ο</sub>	DC Output Source/Sink Current	±12.5	mA
I <sub>CC</sub>	DC Supply Current Per Supply Pin	±25	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	±25	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
TJ	Junction Temperature Under Bias	150	°C
MSL	Moisture Sensitivity	Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>	ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 N/A	V
ILATCHUP	Latchup Performance Above V <sub>CC</sub> and Below GND at 125°C (Note 5)	±500	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

2. Tested to EIA / JESD22-A114-A.

3. Tested to EIA / JESD22-A115-A.

4. Tested to JESD22-C101-A.

5. Tested to EIA / JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit	
V <sub>CC</sub>	Positive DC Supply Voltage			5.5	V
V <sub>IN</sub>	Digital Input Voltage		0	5.5	V
V <sub>OUT</sub>	Output Voltage		0	5.5	V
T <sub>A</sub>	Operating Free–Air Temperature		-55	+125	°C
$\Delta t / \Delta V$	Input Transition Rise or Fall Rate V <sub>C</sub> V <sub>C</sub>	CC = 3.3 V ± 0.3 V CC = 5.0 V ± 0.5 V	0 0	No Limit No Limit	ns/V

## DC ELECTRICAL CHARACTERISTICS

			V <sub>CC</sub>		T <sub>A</sub> = 25 °C	;	<b>T</b> <sub>A</sub> = -	⊦85°C		55°C to 5°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>T+</sub>	Positive Threshold Voltage		3.0 4.5 5.5	1.85 2.86 3.50	2.0 3.0 3.6	2.2 3.15 3.85		2.2 3.15 3.85		2.2 3.15 3.85	V
V <sub>T-</sub>	Negative Threshold Voltage		3.0 4.5 5.5	0.9 1.35 1.65	1.5 2.3 2.9	1.65 2.46 3.05	0.9 1.35 1.65		0.9 1.35 1.65		V
V <sub>H</sub>	Hysteresis Voltage		3.0 4.5 5.5	0.30 0.40 0.50	0.57 0.67 0.74	1.20 1.40 1.60	0.30 0.40 0.50	1.20 1.40 1.60	0.30 0.40 0.50	1.20 1.40 1.60	V
V <sub>OH</sub>	Minimum High–Level Output	$V_{IN} \le V_{T-MIN}$ $I_{OH}$ = -50 µA	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		1.9 2.9 4.4		V
	Voltage	$\begin{array}{l} V_{IN} \leq V_{T-MIN} \\ I_{OH} = -4 \text{ mA} \\ I_{OH} = -8 \text{ mA} \end{array}$	3.0 4.5	2.58 3.94			2.48 3.80		2.34 3.66		
V <sub>OL</sub>	Maximum Low-Level Output	$V_{IN} \ge V_{T+MAX}$ $I_{OL} = 50 \ \mu A$	2.0 3.0 4.5		0 0 0	0.1 0.1 0.1		0.1 0.1 0.1		0.1 0.1 0.1	V
	Voltage	$\begin{array}{l} V_{IN} \geq V_{T+MAX} \\ I_{OL} = 4 \mbox{ mA} \\ I_{OL} = 8 \mbox{ mA} \end{array}$	3.0 4.5			0.36 0.36		0.44 0.44		0.52 0.52	
I <sub>IN</sub>	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	0 to 5.5			±0.1		±1.0		±1.0	μΑ
I <sub>CC</sub>	Quiescent Supply Current	$0 \le V_{IN} \le V_{CC}$	5.5			1.0		10		40	μΑ

### AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$ )

		v <sub>cc</sub>	Test		T <sub>A</sub> = 25 °	с	T <sub>A</sub> =	+85°C	T <sub>A</sub> = -5 +12		
Symbol	Parameter	(V)	Condition	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation Delay,	3.0 to	C <sub>L</sub> = 15 pF		7.0	12.8	1.0	15	1.0	17	ns
t <sub>PHL</sub>	Input Ă to Output Ÿ	3.6	C <sub>L</sub> = 50 pF		8.5	16.3	1.0	18.5	1.0	20.5	
		4.5 to	C <sub>L</sub> = 15 pF		4.0	8.6	1.0	10	1.0	11.5	
		5.5	C <sub>L</sub> = 50 pF		5.5	10.6	1.0	12	1.0	13.5	
C <sub>IN</sub>	Input Capacitance				5.0	10		10		10	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	5.0			7.0						pF

6.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no-load dynamic power consumption:  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .

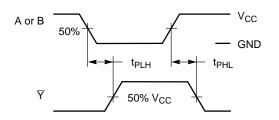
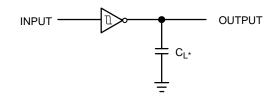
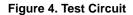


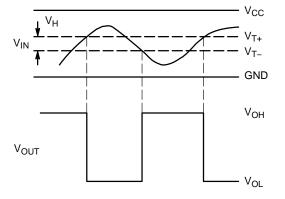
Figure 3. Switching Waveforms

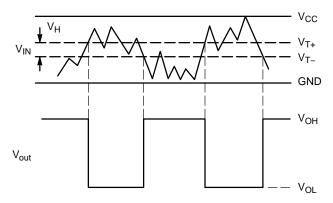


\*Includes all probe and jig capacitance.

A 1–MHz square input wave is recommended for propagation delay tests.







(a) A Schmitt-Trigger Squares Up Inputs With Slow Rise and Fall Times

(b) A Schmitt–Trigger Offers Maximum Noise Immunity

#### Figure 5. Typical Schmitt-Trigger Applications

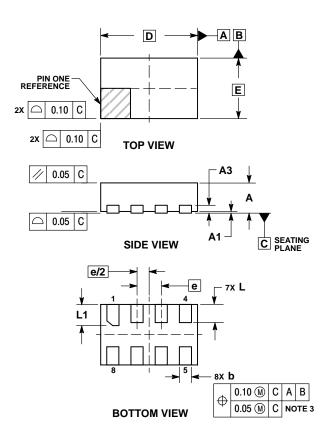
#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NLU3G14MUTAG	UDFN8 (Pb-Free)	3000 / Tape & Reel
NLU3G14DMUTCG	UDFN8, 1.95 x 1.0, 0.5P (Pb-Free)	3000 / Tape & Reel
NLU3G14EMUTCG	UDFN8, 1.6 x 1.0, 0.4P (Pb–Free)	3000 / Tape & Reel
NLU3G14FMUTCG	UDFN8, 1.45 x 1.0, 0.35P (Pb–Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### PACKAGE DIMENSIONS

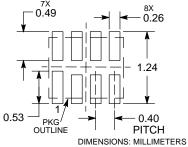
UDFN8 1.6x1.0, 0.4P CASE 517BY ISSUE O



- NOTES:
  DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
  PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

BURF	BURRS AND MOLD FLA					
	MILLIN	MILLIMETERS				
DIM	MIN	MIN MAX				
Α	0.45	0.55				
A1	0.00					
A3	0.13	0.13 REF				
b	0.15	0.25				
D	1.60	BSC				
E	1.00	BSC				
е	0.40 BSC					
L	0.25 0.35					
L1	0.30	0.40				

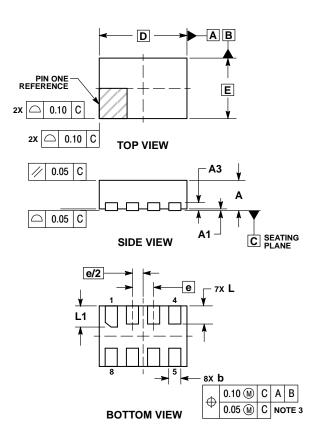
#### RECOMMENDED **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## PACKAGE DIMENSIONS

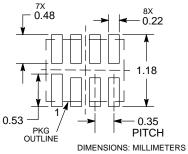
UDFN8 1.45x1.0, 0.35P CASE 517BZ ISSUE O



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  CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
  PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

BURRS AND MOLD FL						
	MILLIN	MILLIMETERS				
DIM	MIN MAX					
Α	0.45	0.55				
A1	0.00 0.05					
A3	0.13 REF					
b	0.15	0.25				
D	1.45	BSC				
Е	1.00	BSC				
е	0.35 BSC					
L	0.25 0.35					
L1	0.30	0.40				

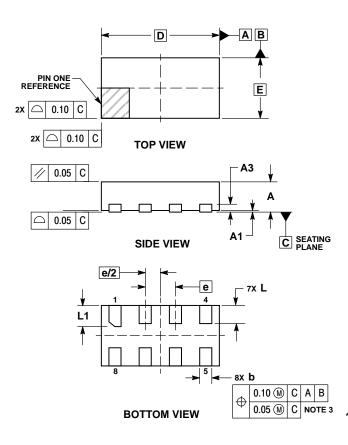
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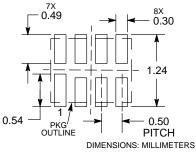
UDFN8 1.95x1.0, 0.5P CASE 517CA ISSUE O



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  CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
  PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

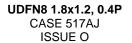
BURRS AND MOLD FI						
	MILLIMETERS					
DIM	MIN MAX					
Α	0.45	0.55				
A1	0.00	0.00 0.05				
A3	0.13 REF					
b	0.15 0.25					
D	1.95	BSC				
Е	1.00	BSC				
е	0.50 BSC					
L	0.25	0.25 0.35				
L1	0.30	0.40				

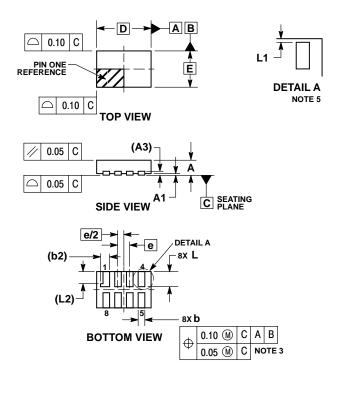
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#### PACKAGE DIMENSIONS



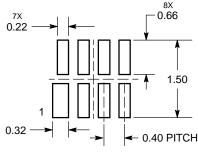


NOTES:

- UTES:
  DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM TERMINAL TIP.
  - MOLD FLASH ALLOWED ON TERMINALS ALONG EDGE OF PACKAGE. FLASH MAY
- NOT EXCEED 0.03 ONTO BOTTOM
- SURFACE OF TERMINALS. DETAIL A SHOWS OPTIONAL CONSTRUCTION FOR TERMINALS. 5

	MILLIMETERS					
DIM	MIN MAX					
Α	0.45	0.55				
A1	0.00	0.05				
A3	0.127	0.127 REF				
b	0.15	0.25				
b2	0.30	REF				
D	1.80	BSC				
Е	1.20	BSC				
е	0.40	BSC				
L	0.45	0.55				
L1	0.00	0.03				
L2	0.40	REF				

#### MOUNTING FOOTPRINT SOLDERMASK DEFINED



DIMENSIONS: MILLIMETERS

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